



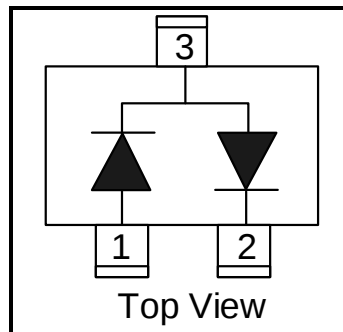
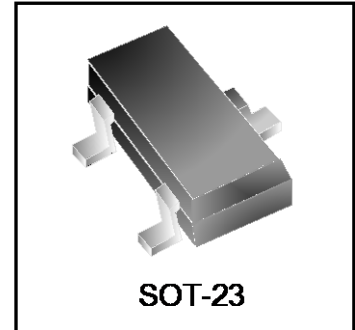
WSR4002T3

Schottky Barrier Diode

Features

- High Conductance
- Low Current Leakage
- Small Outline Surface Mount Package
- RoHS Compliant / Green EMC

Schematic & PIN Configuration



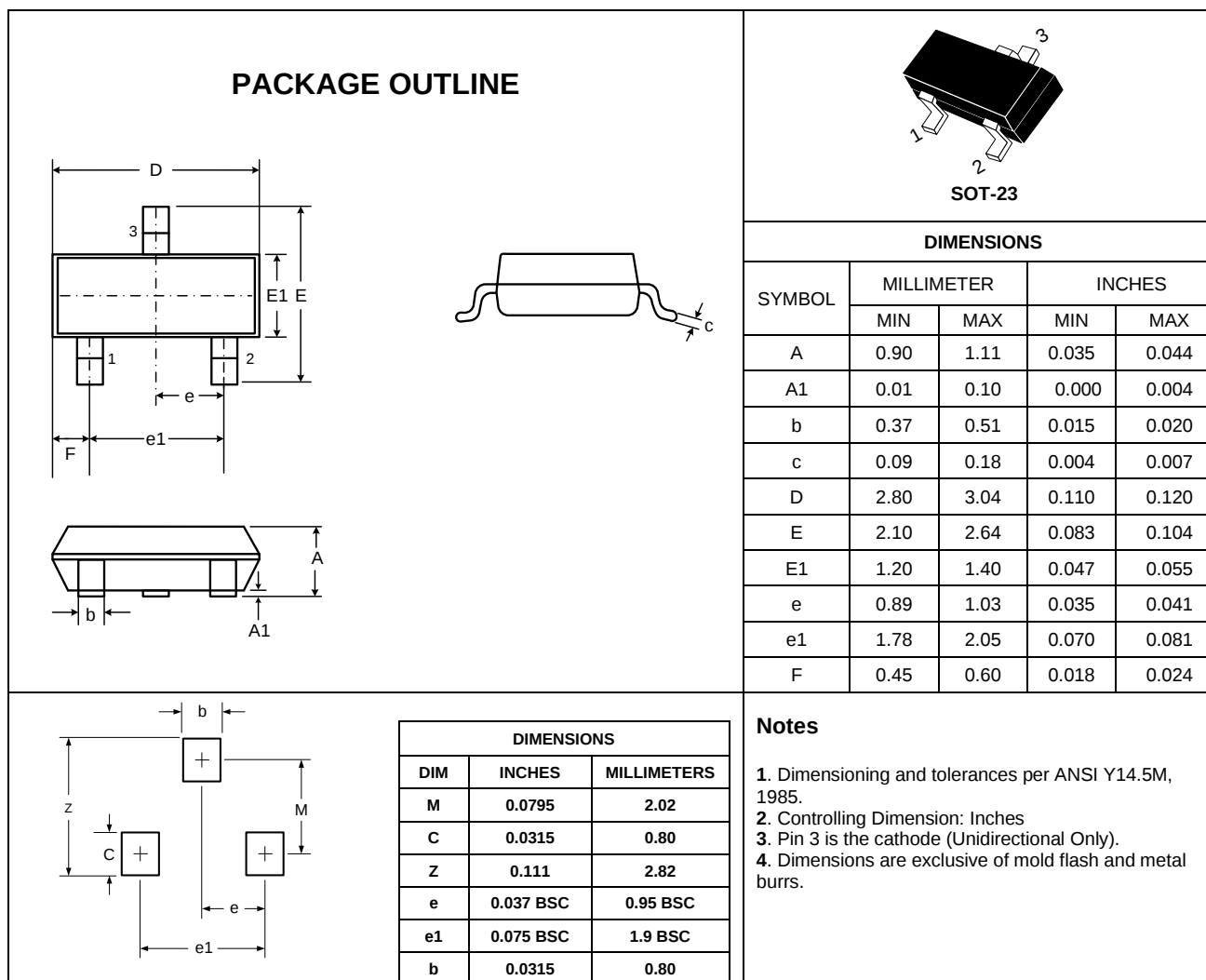
Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Peak Repetitive Peak Reverse Voltage	V_R	40	V
Forward Continuous Current	I_F	200	mA
Power Dissipation	P_D	200	mW
Non-Repetitive Peak Forward Surge Current @ $t=1s$	I_{FSM}	0.6	A
Soldering temperature during	T_j	260	°C
Thermal Resistance Junction to Ambient	R_j	500	°C/W
Junction Temperature	T_J	-55 to 125	°C
Storage Temperature	T_{stg}	-55 to 150	°C

Electrical Characteristics ($T_{amb}=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Reverse breakdown voltage	V_{BR}	$I_R = 10\mu A$	40	-	-	V
Reverse voltage leakage current	I_R	$V_R = 30V$	-	-	200	nA
Forward voltage	V_F	$I_F = 1mA$	-	-	0.38	V
	V_F	$I_F = 40mA$	-	-	1	
Typical Junction Capacitance	C_J	$V_R = 0V, f=1.0MHz$	-	4.5	-	pF
Reverse recovery time	T_{rr}	$I_F=I_R=10mA, I_{(REC)}=1mA$	-	4.5	-	nS

Outline Drawing –SOT-23



Marking Codes

Part Number	WSR4002T3
Marking Code	

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

No.1001, Shiwan (7) Road, Pudong District, Shanghai, P.R.China.201207

Tel: 86-21-68969993 Fax: 86-21-50757680 Email: market@way-on.comWAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

WAYON® is registered trademark of Wayon Corporation.

Specifications are subject to change without notice.
 The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
 Users should verify actual device performance in their specific applications.